

RAJ240055

R-BMS F Quick Start Guide

R16AN0073EJ0101 Rev.1.01 May 16, 2025

Introduction

The RAJ240055 R-BMS F evaluation kit consists of an evaluation module (EVM), a USB System Management Bus (SMBus) and an interface adaptor which allow users to evaluate their battery management system using Renesas RAJ240055 Li-ion battery Fuel Gauge IC (FGIC).

Additionally, the kit comes with R-BMS F firmware, which is fixed and easy to use software requiring no additional development with user configurable settings for determining the different thresholds of the device.

This User's Manual provides detailed information of the evaluation kit and how to set it up to construct 2 - 4 Li-ion battery cell series to start operation and performance evaluation.

Target Device

RAJ240055

Note:

Default cell count setting of each EVM is as follows. To amend the cell count, full package is needed.

RAJ240055 R-BMS F: 4 cell

Windows Decimal Symbol setting must be a period "." in order for the GUI to launch.

Refer to the URL below and download the package for more details.

https://www.renesas.com/en/products/power-management/battery-management/battery-fuel-gauges/rtk0ef0163dk0002bu-raj240055-fixed-firmware-evaluation-kit-battery-management?queryID=b9dc5a565b1928dc40b743b67ae7347a

Contents

1.	Evaluation Kit Features & Contents	3
1.1	Features	3
1.2	Hardware Contents	3
1.3	Performance Specification Summary	3
1.4	Required Equipment	3
1.5	Evaluating with a Load Current エラー! ブックマークが定義されていません	u.
2.	Function Outline	5
2.1	Features	5
2.2	Function outline	5
3.	SMBus Commands	6
4.	Quick Bootup/Start	7
4.1	Reducing the Cell Count	7
5.	R-BMS F_Tool	8
5.1	Software Requirements	8
Rev	rision History	Ç

1. Evaluation Kit Features & Contents

This chapter overviews the EVM features and hardware contents.

1.1 Features

- A complete evaluation system for the RAJ240055 with 2-4 cell Li-ion battery.
- An optimized circuit module for 2-cell to 4-cell configuration for quick setup.
- SMBus I/F communication.
- A built-in resistor cell simulator for quick setup and minimum wire connections.
- A GUI based PC software for configuration.

1.2 Hardware Contents

The R-BMS F evaluation kit comes with the hardware items shown in Table 1-1 below.

Table 1-1 R-BMS F Evaluation Kit Contents

Item	Description
R-BMS F EVM	EVM for evaluating R-BMS F with RAJ240055 FGIC.
USB SMBus Converter (I/F)	USB SMBus interface adapter.
Cables	A USB cable for connecting the SMBus I/F to the PC.
	A serial cable to connect the SMBus I/F to the EVM.

1.3 Performance Specification Summary

The R-BMS F evaluation kit specifications are shown in Table 1-2 below.

Table 1-2 Performance Specification Summary

Specification	Min	TYP	Max	Unit
Input voltage Pack+ to Pack-			25	V
Battery voltage V1/V2/V3/V4	2.5		4.2	V
Charge and discharge current	0		15	Α

Note: Board cooling may be required for continuous operation at or below the maximum current.

1.4 Required Equipment

The following equipment is required to operate the EVM.

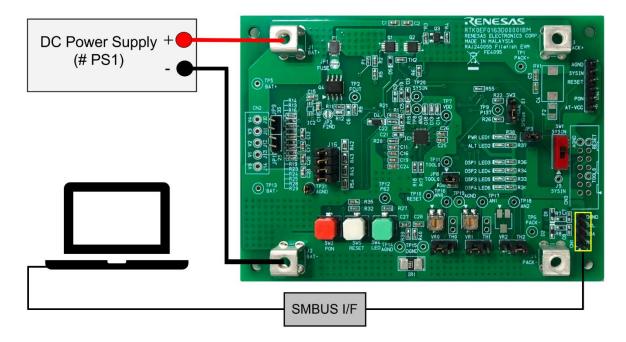
Table 1-3 Required Equipment List

Item	Symbol	Description
DC power supply 1	PS#1	For Battery simulation
		Bipolar DC power supply will be needed for charger test.
DC power supply 2	PS#2	Optional and may be needed to simulate the charger.
DC load	DCL	Optional and may be needed to simulate the system
or assorted resistors		load.
		A bipolar DC power supply can be used instead.
Computer with a USB port	-	Windows operating system is required.

Note: Additional equipment may be needed to operate the EVM with a more extensive test.



1.5 EVM Connection with Minimum Configuration (4 cells)



2. Function Outline

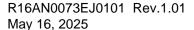
2.1 Features

- High accuracy Voltage, Current, and Temperature detection and safety protection.
- Safety and outperformed charging controlling.
- Accurate capacity calculation
- Make less power consumption by power saving control.
- Supports the Smart Battery Data specification V1.1
- Supports various system by parameter of FlashROM (Fixed data / Own data / Flexible data)
- Supports on-board firmware updating via SMBus
- Current Range: -32768 mA to 32767 mA Note

Note: Allowable current of EVB is 15A. Refer to Section 1.3 for more details.

2.2 Function outline

- Voltage, Current, Temperature measurement
- Remaining Capacity (RC) Calculation
- Relative State Of Charge (RSOC) Calculation
- Full Charge Capacity (FCC) update
- Initial Calibration mode for accurate measurement
- Capacity correction by Lookup table
- Mode transition: Normal, Sleep, Shutdown, Fail
- Over Current, Over / Under Voltage, and Over Temperature protection
- Fuse Blow
- RMA Data & Fault Logging
- LED Display Module (optional)
- JEITA Charging (optional)
- Master Communication (optional)





3. SMBus Commands

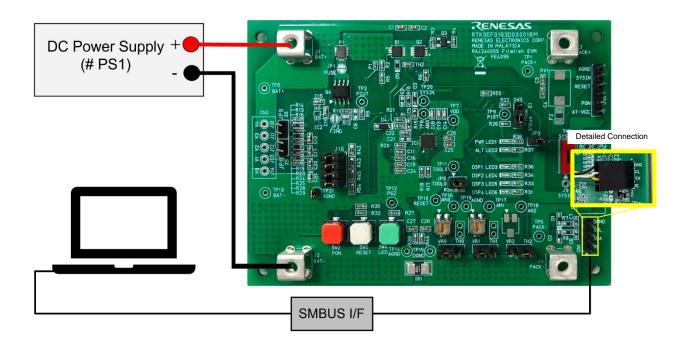
Some commands are not listed. Refer to firmware specification for more details.

Function	Code	Access	Unit	Description
Temperature()	0x08	RW	0.1K	The cell-pack's internal temperature
Voltage()	0x09	RW	mV	The cell-pack voltage
Current()	0x0A	RW	mA	The current being supplied through the battery's terminals
RelativeStateOfCharge()	0x0D	RW	%	The predicted remaining battery capacity expressed as a
				percentage
RemainingCapacity()	0x0F	RW	mAh	The predicted remaining battery capacity
FullChargeCapacity()	0x10	RW	mAh	The predicted pack capacity when it is fully charged
ChargingCurrent()	0x14	RW	mA	Desired charging rate to the Smart Battery Charger
ChargingVoltage()	0x15	RW	mV	Desired charging voltage to the Smart Battery Charger
BatteryStatus()	0x16	RW	Bit flags	The Smart Battery's status with Alarm and Status Bit Field 15
CycleCount()	0x17	RW	cycle	The number of cycles the battery has experienced
DesignCapacity()	0x18	RW	mAh	The theoretical capacity of a new pack
ManufactureDate()	0x1B	RW/WW	-	The date the cell pack was manufactured in a packed
SerialNumber()	0x1C	RW/WW	-	The serial number
ManufacturerName()	0x20	BR	String	The character array containing the battery's manufacturer's name
DeviceName()	0x21	BR	String	The character string that contains the battery's name
DeviceChemistry()	0x22	BR	String	The partial list of chemistries and their expected abbreviations
ManufacturerData()	0x23	BR	String	The manufacturer data contained in the battery
OperationStatus()	0x41	RW	-	The cell-pack's operation status Mode number
FETTemp()	0x44	RW	0.1K	The FET temperature
PACKVoltage()	0x47	RW	mV	The cell-pack output voltage
StateOfHealth()	0x48	RW	%	The predicted percentage of cell aging
VoltageOfCellx()	0x60-0x63	RW	mV	Each cell voltage (0x60 is the bottom, 0x63 is the top)
FirmwareVersion()	0xF1	RW	-	The firmware version
FirmwareSubVersion()	0xF2	RW	-	The firmware subversion

4. Quick Bootup/Start

Refer to user's manual in the package for more details. To use SMBus I/F, package would be needed.

- 1. Configure the cell count. For more details, refer to in section 4.1.
- 2. Connect the power supply (PS#1) between BAT+ and BAT- terminals.
- 3. Adjust the DC power supply (PS#1) setting to a value between 3V to 4.2V per cell.
- 4. Default series number of cell setting is 4 cell.
- 5. Apply voltage between BAT+ and BAT- terminals using the DC power supply (PS#1).
- 6. Press the "PON" switch (SW1) to boot-up the system from power down mode.
- 7. Confirm the LED status. LED1 (PWR) will turn on (green) when it succeeds in booting up. **Note:** if JP3 is not connected, LED1 will not turn ON.
- 8. The battery pack status can be monitored via SMBus connector (CN1).



4.1 Reducing the Cell Count

The R-BMS F solution supports 2 to 4 cells. The EVM utilizes the Jumpers JP9 and JP10 to specify the number of cells to be used when applying voltage to the battery terminals. see Table 4-1 below.

Table 4-1 Reducing the Cell Count

Cell Count	JP9	JP10
2 cells	closed	closed
3 cells	closed	open
4 cells	open	open

5. R-BMS F_Tool

The R-BMS F_Tool is a GUI software used for monitoring and evaluating the R-BMS F EVM. It provides the features shown in Table 5-1. For more details, refer to the R-BMS F Tool manual in the package.

Menu Name **Function/Description** HOME Home Screen. SYSTEM MONITOR Read/Log the SMBus register data. **FIXED DATA** Battery Parameter read/write. **FLEXIBLE DATA** Latest system data read/write. OWN DATA Board level calibration read/write. **CALIBRATION** Perform board level calibration. Firmware flash memory (Fixed/Own, Flexible) data update FLASH UPDATE **FACTORY DEFAULT** EVM roll back function **FUNCTION CONFIG** Easy battery parameter setting function

Table 5-1 Function Overview



Figure 5-1 R-BMS F TOOL Overview.

5.1 Software Requirements

The R-BMS F Tool requires a Windows 10 or later system.

Revision History

		Description		
Rev.	Date	Page	Summary	
1.00	Mar. 3, 2025		First release	
1.01	May 16, 2025		Add SMBus Commands	
			Add Quick Bootup/start	

General Precautions in the Handling of Microprocessing Unit and Microcontroller Unit Products

The following usage notes are applicable to all Microprocessing unit and Microcontroller unit products from Renesas. For detailed usage notes on the products covered by this document, refer to the relevant sections of the document as well as any technical updates that have been issued for the products.

- 1. Precaution against Electrostatic Discharge (ESD)
 - A strong electrical field, when exposed to a CMOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop the generation of static electricity as much as possible, and quickly dissipate it when it occurs. Environmental control must be adequate. When it is dry, a humidifier should be used. This is recommended to avoid using insulators that can easily build up static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work benches and floors must be grounded. The operator must also be grounded using a wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions must be taken for printed circuit boards with mounted semiconductor devices.
- 2. Processing at power-on
 - The state of the product is undefined at the time when power is supplied. The states of internal circuits in the LSI are indeterminate and the states of register settings and pins are undefined at the time when power is supplied. In a finished product where the reset signal is applied to the external reset pin, the states of pins are not guaranteed from the time when power is supplied until the reset process is completed. In a similar way, the states of pins in a product that is reset by an on-chip power-on reset function are not guaranteed from the time when power is supplied until the power reaches the level at which resetting is specified.
- 3. Input of signal during power-off state
 - Do not input signals or an I/O pull-up power supply while the device is powered off. The current injection that results from input of such a signal or I/O pull-up power supply may cause malfunction and the abnormal current that passes in the device at this time may cause degradation of internal elements. Follow the guideline for input signal during power-off state as described in your product documentation.
- 4. Handling of unused pins
 - Handle unused pins in accordance with the directions given under handling of unused pins in the manual. The input pins of CMOS products are generally in the high-impedance state. In operation with an unused pin in the open-circuit state, extra electromagnetic noise is induced in the vicinity of the LSI, an associated shoot-through current flows internally, and malfunctions occur due to the false recognition of the pin state as an input signal become possible.
- 5. Clock signals
 - After applying a reset, only release the reset line after the operating clock signal becomes stable. When switching the clock signal during program execution, wait until the target clock signal is stabilized. When the clock signal is generated with an external resonator or from an external oscillator during a reset, ensure that the reset line is only released after full stabilization of the clock signal. Additionally, when switching to a clock signal produced with an external resonator or by an external oscillator while program execution is in progress, wait until the target clock signal is stable.
- 6. Voltage application waveform at input pin
 - Waveform distortion due to input noise or a reflected wave may cause malfunction. If the input of the CMOS device stays in the area between V_{IL} (Max.) and V_{IH} (Min.) due to noise, for example, the device may malfunction. Take care to prevent chattering noise from entering the device when the input level is fixed, and also in the transition period when the input level passes through the area between V_{IL} (Max.) and V_{IH} (Min.).
- 7. Prohibition of access to reserved addresses
 - Access to reserved addresses is prohibited. The reserved addresses are provided for possible future expansion of functions. Do not access these addresses as the correct operation of the LSI is not guaranteed.
- 8. Differences between products
 - Before changing from one product to another, for example to a product with a different part number, confirm that the change will not lead to problems. The characteristics of a microprocessing unit or microcontroller unit products in the same group but having a different part number might differ in terms of internal memory capacity, layout pattern, and other factors, which can affect the ranges of electrical characteristics, such as characteristic values, operating margins, immunity to noise, and amount of radiated noise. When changing to a product with a different part number, implement a system-evaluation test for the given product.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Power Management IC Development Tools category:

Click to view products by Renesas manufacturer:

Other Similar products are found below:

ISLUSBI2CKITIZ ISL2109012EV1Z ISL8002AEVAL1Z ISL91108IIA-EVZ DCD48AP480T320A50 AP62250WU-EVM AP61102Z6EVM SAMPLEBOXILD8150TOBO1 AP61100Z6-EVM AP62300Z6-EVM Si8285_86v2-KIT EVALM7HVIGBTPFCINV4TOBO1
REFSHA35IMD111TSYSTOBO1 TDINV3000W50B-KIT NCP1681CCM1KWGEVB SI83401BAA-KIT SI83402BAA-KIT SI83411BAAKIT SI83412BAA-KIT MIKROE-5294 MIKROE-5374 EVB81332 MIKROE-5019 BTG70902EPLDAUGHBRDTOBO1 TAB-48017
APEK89307KET-01-T 64010 EVAL6EDL04I065PRTOBO1 EVB81340-100W RTKA489EPRDK0010BU DC3107A EVL4248-QV-00A
EVQ4371-V-1000-00A EVL28167-B-Q-00A EV6631B-L-00A EVL1608C-TL-00A APEK5932GES-01-T-01 R1810Z015A-EV
BD9E203FP4-EVK-001 MOS7GENERICPOWBOARDTOBO1 EVAL7126G100VGANCTOBO1 EVALFFXMR20W2M1HXTOBO1
APEK49100KJP-A-03-T TEA2017DK1007 MIKROE-5886 APEK85000GEJ-01-T 1EDI3051EVALBOARDTOBO2
TLD609812BEVALTOBO1 EVQ4322C-D-00A EVM3612-LQ-00A